NSN 5962-01-358-1172

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-358-1172

Body Length: 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** Between 0.172 inches and 0.217 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and ultraviolet erasable and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Current Rating Per Characteristic:** 3.00 milliamperes reverse current, dc blank **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.6 volts power source and 14.0 volts power source **Capitance Rating Per Characteristic:** 12.00 input picofarads and 14.00 output picofarads **Memory Device Type: Eprom Special Features:** Nuclear hardness critical items **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

28 printed circuit

Terminal Type And Quantity:

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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